



# N-Channel 20-V (D-S) Fast Switching MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$r_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ)		
20	0.0062 @ V <sub>GS</sub> = 4.5 V	19.5	17.5		
	0.0098 @ V <sub>GS</sub> = 2.5 V	15.5	17.5		

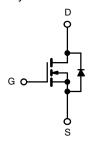
### **FEATURES**



- TrenchFET® Power MOSFET
- New Low Thermal Resistance PowerPAK® Package with Low 1.07-mm Profile
- COMPLIANT
- PWM Optimized
- 100% R<sub>a</sub> Tested

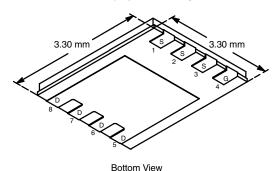
### **APPLICATIONS**

• Synchronous Rectification



N-Channel MOSFET





Ordering Information: Si7106DN-T1—E3 (Lead (Pb)-Free)

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	10 secs	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	20		V	
Gate-Source Voltage		V <sub>GS</sub>	± 12			
O-ations David Ones 4/T 450003	T <sub>A</sub> = 25°C		19.5	12.5		
Continuous Drain Current (T <sub>J</sub> = 150°C) <sup>a</sup>	T <sub>A</sub> = 70°C	l <sub>D</sub>	15.6	10.0		
Pulsed Drain Current		I <sub>DM</sub>	60		Α	
Continuous Source Current (Diode Conduction) <sup>a</sup>		IS	3.2	1.3		
Single Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	IAS 30   EAS 45		Α	
Single Avalanche Energy	L = 0.1 IIIII	E <sub>AS</sub>			mJ	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25°C	В	3.8	1.5	w	
	T <sub>A</sub> = 70°C	P <sub>D</sub>	2.0	0.8		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150		°C	
Soldering Recommendations (Peak Temperature)b,c				260	O	

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
	t ≤ 10 sec	R <sub>thJA</sub>	24	33			
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		65	81	°C/W		
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	1.9	2.4			

#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. See Solder Profile (http://www.vishay.com/doc?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

# **Vishay Siliconix**



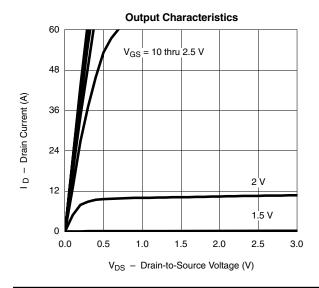
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Static				-71		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.6		1.5	V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS}$ = 0 V, $V_{GS}$ = $\pm$ 12 V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55 ^{\circ}\text{C}$			1 5	μΑ
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	40			Α
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS} = 4.5$ V, $I_D = 19.5$ A $V_{GS} = 2.5$ V, $I_D = 15.5$ A		0.0051	0.0062 0.0098	Ω
Forward Transconductance <sup>a</sup>	9fs	$V_{DS} = 15 \text{ V}, I_D = 19.5 \text{ A}$		105	0.0030	S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = 3.2 A, V <sub>GS</sub> = 0 V		0.8	1.2	V
Dynamic <sup>b</sup>	- 1			·		
Total Gate Charge	Qg			17.5	27	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 10 \text{ V}, \ V_{GS} = 4.5 \text{ V}, \ I_{D} = 19.5 \text{ A}$		6.6		nC
Gate-Drain Charge	$Q_{gd}$			2.8		
Gate-Resistance	R <sub>g</sub>	f = 1 MHz	0.7	1.4	2.1	Ω
Turn-On Delay Time	t <sub>d(on)</sub>			25	40	
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 10 $\Omega$		15	25	ns
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		50	75	
Fall Time	t <sub>f</sub>			12	20	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 3.2 A, di/dt = 100 A/μs		30	60	Ī

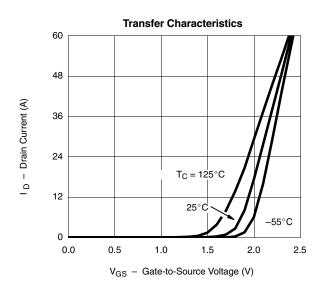
#### Notes

- Pulse test; pulse width  $\leq 300~\mu s$ , duty cycle  $\leq 2\%$ . Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



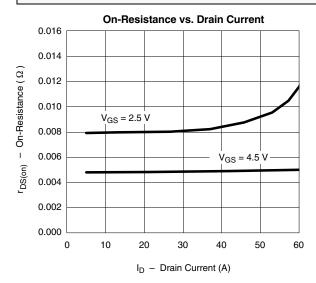


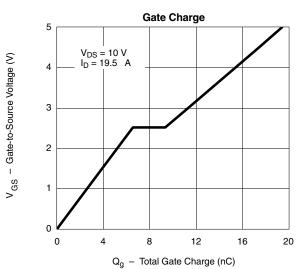


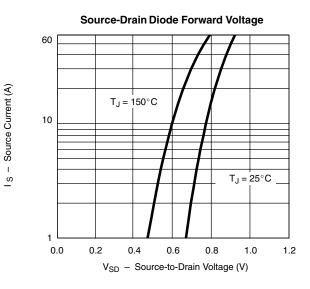


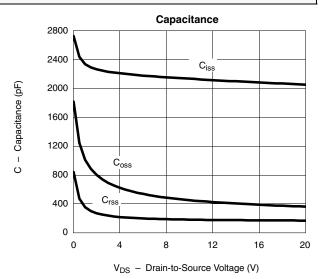
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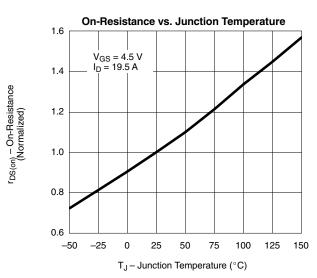
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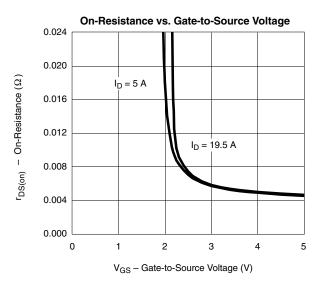








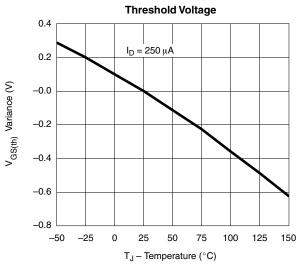


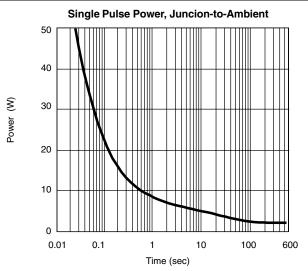


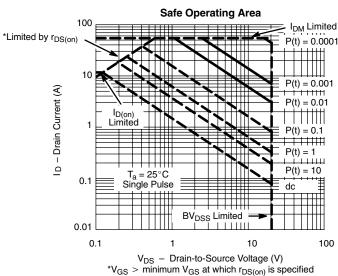
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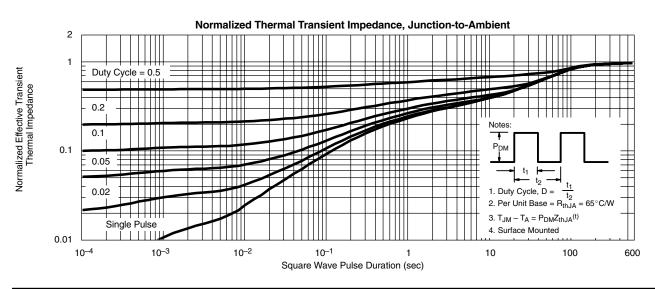


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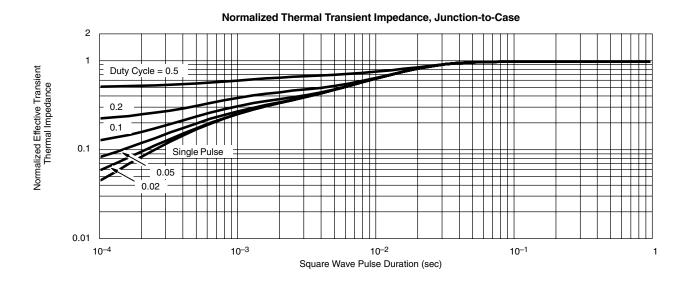








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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?73142">http://www.vishay.com/ppg?73142</a>

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Document Number: 91000 www.vishay.com Revision: 08-Apr-05